





RELEASE Ø DATA SHEET

#### **FEATURES**

- Flexible Bias
- $\bullet$  Internally Matched to 50  $\Omega$
- Process: GaAs pHEMT
- Compact 1.5 x 1.5 mm DFN-6 Package
- RoHS Compliant

#### Reference: 5 V / 90 mA / 1.9 GHz

Gain: 10.2 dBOIP3: 36 dBm

• OP1dB: 20 dBm

• EVB Noise Figure: 3.1 dB

#### **APPLICATIONS**

- Systems Requiring Flat Gain
- Linear Driver Amplifier
- Small Cells and Cellular Repeaters
- IF Amplifier

#### **M** DESCRIPTION

The GRF2010 is a broadband gain block with exceptional gain flatness for small cell, wireless infrastructure, and other high-performance applications. It exhibits outstanding broadband noise figure (NF), linearity over 400 to 4000 MHz with a single match, and can be optimized for applications from 50 MHz to 5 GHz.

The device can be operated from a supply voltage of 2.7 to 8 V with a selectable  $I_{DDQ}$  range of 15 to 90 mA for optimal efficiency and linearity.

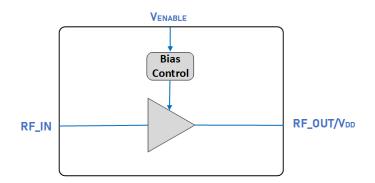
The GRF2010 is internally matched to 50  $\Omega$  at the input and output ports, needing only external DC blocks and a bias choke on the output.

Please consult with the GRF applications engineering team for custom tuning/evaluation board data and device S-parameters.

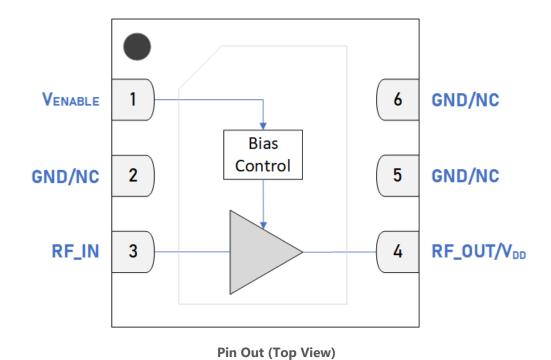
Additional tunes can be found on the GRF2010 "Custom Tunes" product page: GRF2010 Custom Tunes

# ORDERING INFORMATION Buy it Now

### **M** BLOCK DIAGRAM











# **Pin Assignments**

Pin	Name	Description	Note
1	V <sub>ENABLE</sub>	Enable Voltage Input	$V_{ENABLE}$ and series resistor set $I_{DDQ}$ . $V_{ENABLE} \le 0.2$ volts disables device. On-die pull down resistor will turn the device off if this node is allowed to float. Note: Pin 1 voltage should not exceed 3.0 V due to excessive resulting $I_{ENABLE}$
2, 5, 6	GND/NC	Ground or No Connect	No internal connection to die.
3	RF_IN	RF Input	Internally matched to 50 $\Omega$ . An external DC blocking capacitor must be used.
4	RF_OUT/V <sub>DD</sub>	RF Output	Internally matched to 50 $\Omega$ . $V_{DD}$ must be applied through an RF choke to this pin.
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.



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## **Absolute Ratings**

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V <sub>DD</sub>	0	9	V
RF Input Power: Load VSWR < 2:1, $V_{DD} \le 8 \text{ V}$ .	P <sub>IN MAX</sub>		27	dBm
Operating Temperature (Package Base)	T <sub>PKG BASE</sub>	-40	115	°C
Maximum Channel Temperature (MTTF > 10 <sup>6</sup> Hours)	T <sub>MAX</sub>		170	°C
Maximum Dissipated Power at 105 °C.	P <sub>DISS MAX</sub>		1	W
Maximum Dissipated Power at 115 °C.	P <sub>DISS MAX</sub>		0.8	W

#### **Electrostatic Discharge**

Human Body Model	НВМ	250		V
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#### Storage

Storage Temperature	T <sub>STG</sub>	-65	150	°C
Moisture Sensitivity Level	MSL		1	



**Caution! ESD Sensitive Device.** 

**Exceeding Absolute Maximum Rating conditions may cause permanent damage.** 

Note: For additional information, please refer to Manufacturing Note MN-001 - Packaging and Manufacturing Information.



All Guerrilla RF products are provided in RoHS compliant lead (Pb)-free packaging. For additional information, please refer to the Certificate of RoHS Compliance.





## **Recommended Operating Conditions**

Davamatav	Symbol	Specification			11 :4	Caralitica
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Supply Voltage	V <sub>DD</sub>	2.7	5	9	V	
Operating Temperature (Package Base)	T <sub>PKG BASE</sub>	-40		115	°C	
RF Frequency Range	F <sub>TEST</sub>	0.05	1.9	5	GHz	Typical application schematic with external matching components (note 1 & 2).
RF_IN Port Impedance	Z <sub>RFIN</sub>		50		Ω	Single ended.
RF_OUT Port Impedance	Z <sub>RFOUT</sub>		50		Ω	Single ended.

**Note 1:** Operation outside of this range is supported by using different custom tunes. Examples of other optimized tunes can be found here: <u>GRF2010 Custom Tunes</u>

**Note 2:** Contact the Guerrilla RF applications team for guidance on optimizing the tuning of the device for alternative bands.





## **Nominal Operating Parameters - General**

The following conditions apply unless noted otherwise: typical application schematic using the 0.4 to 4 GHz tuning set,  $50~\Omega$  system impedance, M5 =  $700~\Omega$ ,  $V_{DD}$  = 5~V,  $V_{ENABLE}$  = 5~V,  $I_{DD}$  = 90~mA,  $F_{TEST}$  = 1.9~GHz,  $T_{PKG~BASE}$  =  $25~^{\circ}C$ . Evaluation board losses are included within the specifications.

Parameter	Symbol	Specification			Unit	Condition
raiailletei	Syllibol	Min.	Тур.	Max.	Offic	Condition
Supply Current	I <sub>DD</sub>		90		mA	$V_{DD} = 5 \text{ V}, V_{ENABLE} = 5 \text{ V}.$
Enable Current	I <sub>ENABLE</sub>		5	10	mA	
Switching Rise Time	tRISE		600		ns	Disabled Mode to Gain Mode. POUT = 0 dBm (note 3).
Switching Fall Time	tFALL		1000		ns	Gain Mode to Disabled Mode. POUT = 0 dBm (note 4).

#### **Disabled Mode**

Leakage Current	I <sub>LEAKAGE</sub>	1	μΑ	$V_{DD} = 5 \text{ V}, V_{ENABLE} = 0 \text{ V}.$

#### **Thermal Data**

Thermal Resistance (Infrared Scan)	Θ <sub>ЈС</sub>		65		°C/W	On Standard Evaluation Board (note 5).
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**Note 3**: Switching time: 50% of V<sub>ENABLE</sub> to 90% of P<sub>OUT</sub>. **Note 4:** Switching time: 50% of V<sub>ENABLE</sub> to 10% of P<sub>OUT</sub>.

**Note 5:** MTTF >  $10^6$  hours for  $T_{CHANNEL}$  < 170 °C.



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## **Nominal Operating Parameters - RF**

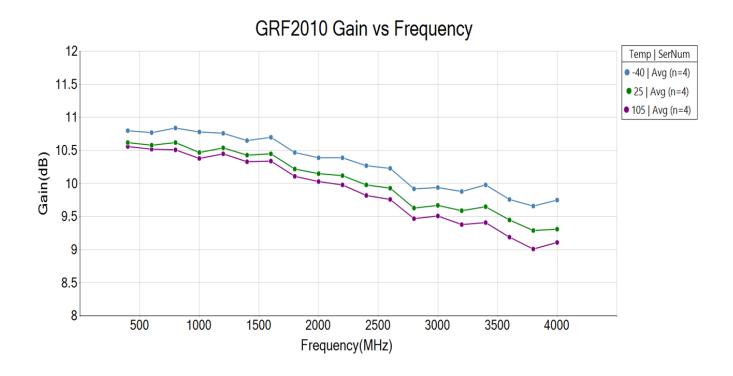
The following conditions apply unless noted otherwise: typical measurement schematic using the 0.4 to 4 GHz tuning set, 50  $\Omega$  system impedance, M5 = 700  $\Omega$ , V<sub>DD</sub> = 5 V, V<sub>ENABLE</sub> = 5 V, I<sub>DD</sub> = 90 mA, F<sub>TEST</sub> = 1.9 GHz, T<sub>PKG BASE</sub> = 25 °C. Evaluation board losses are included within the specifications.

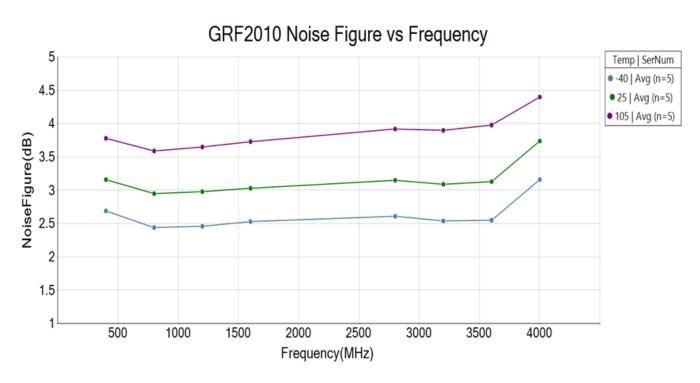
Parameter	Symbol	Specification			Unit	Condition	
Parameter	Symbol	Min.	Тур.	Max.	Onit	Condition	
Gain	S21	8.9	10.2		dB	V <sub>DD</sub> = 5 V, V <sub>ENABLE</sub> = 5 V	
Noise Figure	NF		3.1		dB	On standard evaluation Board.	
Output 3rd Order Intercept Point	OIP3		36		dBm	+2 dBm P <sub>OUT</sub> per tone at 2 MHz spacing (1899 and 1901 MHz).	
Output 1 dB Compression Power	OP1dB	17.5	20		dBm		





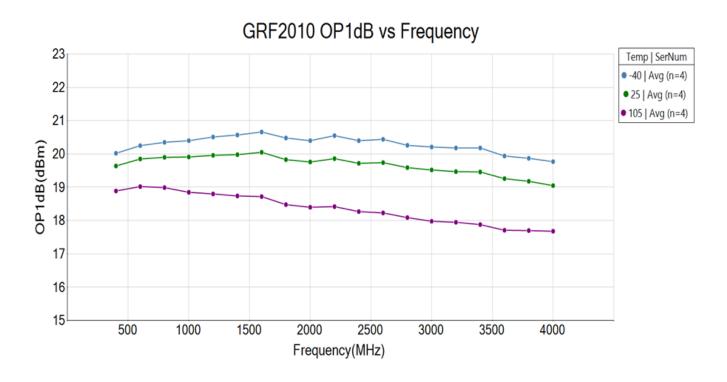
## **GRF2010 Typical Operating Curves: 0.4 to 4 GHz Tune**

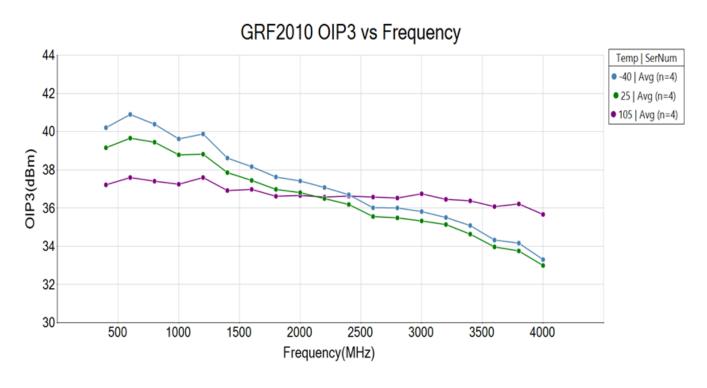




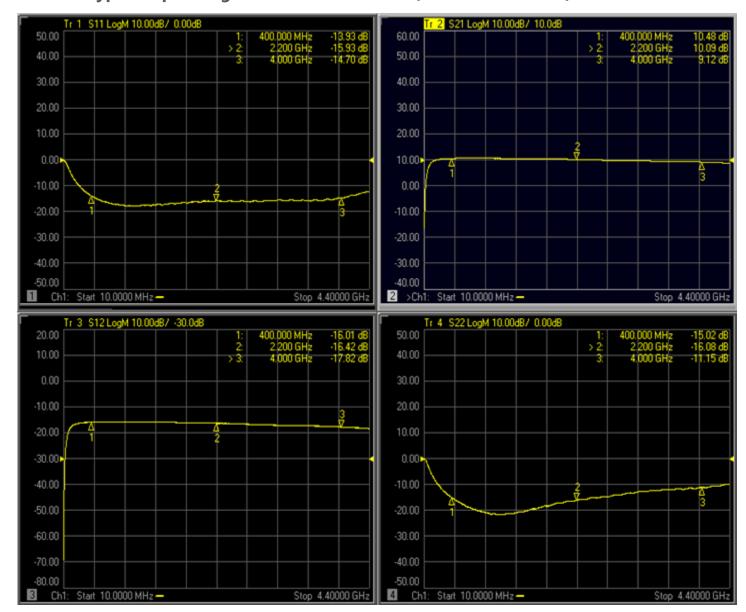


## **GRF2010 Typical Operating Curves: 0.4 to 4 GHz Tune**



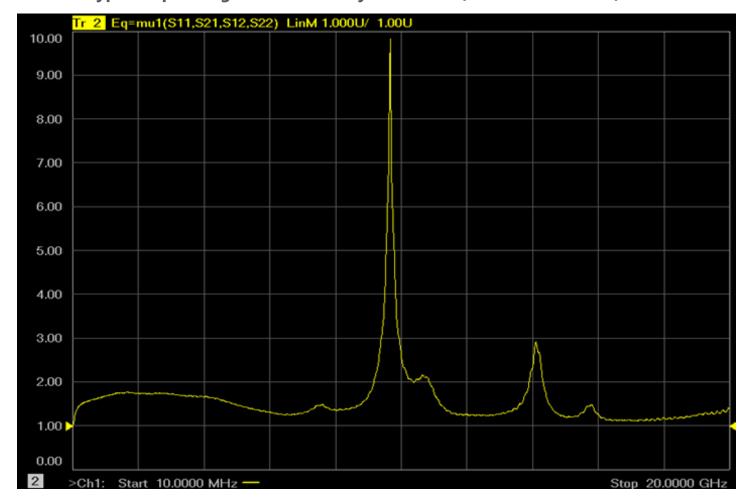


## **GRF2010 Typical Operating Curves: S-Parameters (0.4 to 4 GHz Tune)**





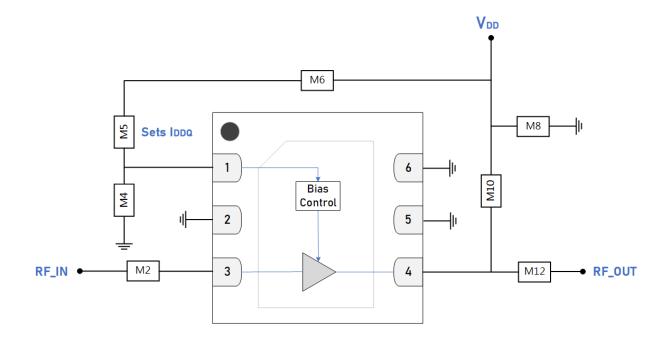
## **GRF2010 Typical Operating Curves: Stability Mu Factor (10 MHz to 20 GHz)**



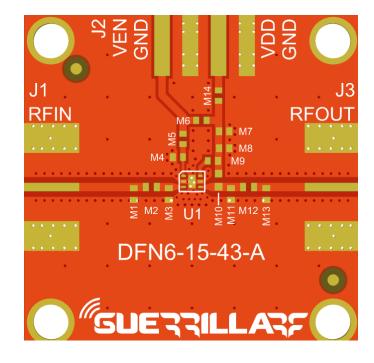
Note: Mu prime factor ≥ 1.0 implies unconditional stability.







**GRF2010 Standard Evaluation Board Schematic** 



**GRF2010 Evaluation Board Assembly Diagram** 

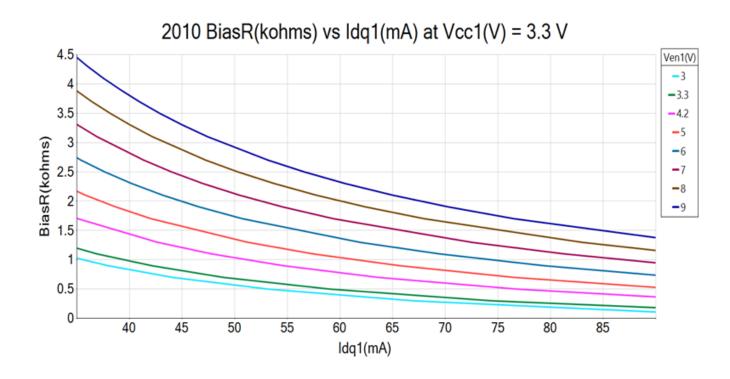


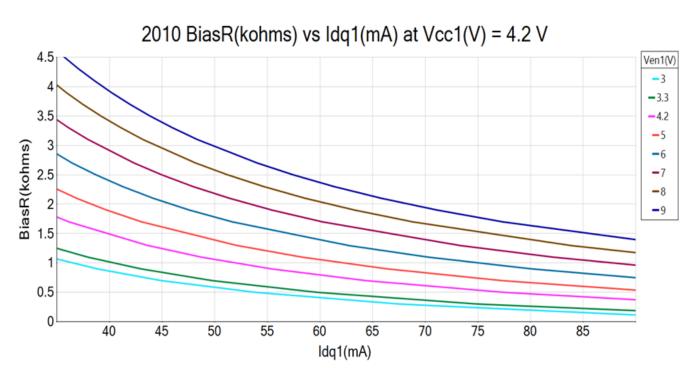
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# **GRF2010 Evaluation Board Assembly Diagram Reference: 0.4 to 4 GHz Tune**

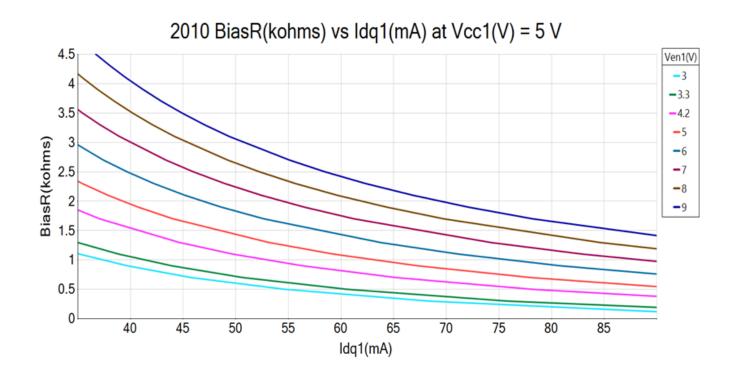
Component	Туре	Manufacturer	Family	Value	Package Size	Substitution
M2	Capacitor	Murata	GRM	100 pF	0402	ok
M4	Capacitor	Murata	GRM	100 pF	0402	ok
M5 (Sets I <sub>DDQ</sub> )	Resistor	Various	5%	700 Ω	0402	ok
M6	Resistor (Jumper)	Various	5%	0 Ω	0402	ok
M8	Capacitor	Murata	GRM	0.1 μF	0402	ok
M10	Inductor	Murata	LQG	47 nH	0402	ok
M12	Capacitor	Murata	GRM	100 pF	0402	ok
Evaluation Board	DFN6-15-43-A					

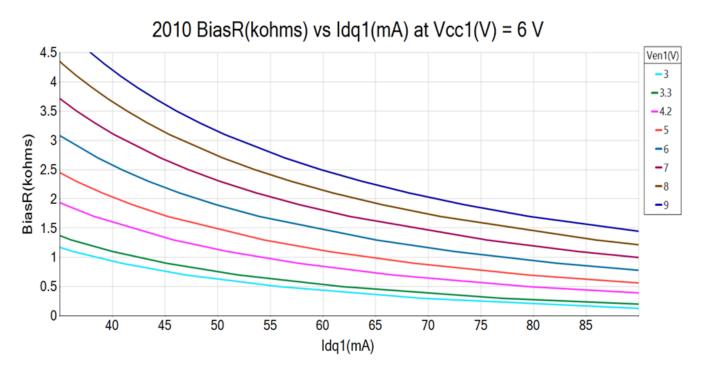




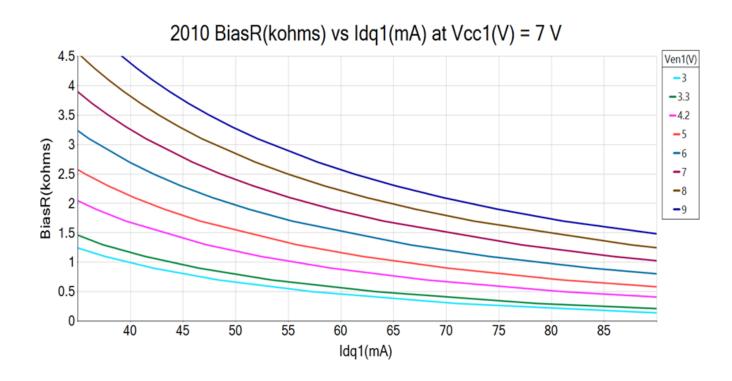


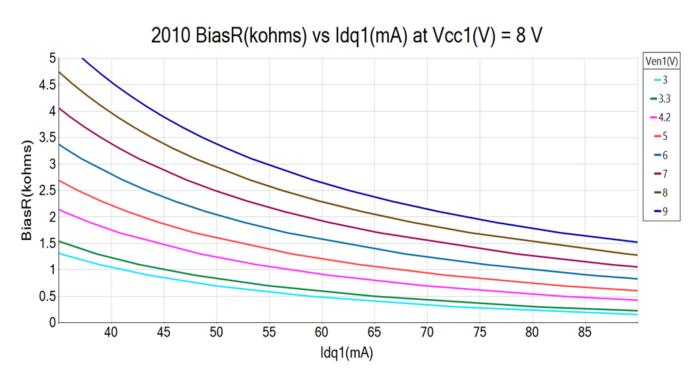






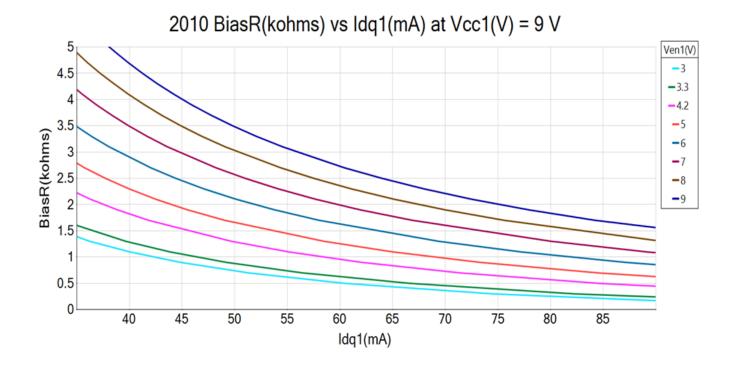




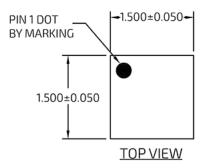


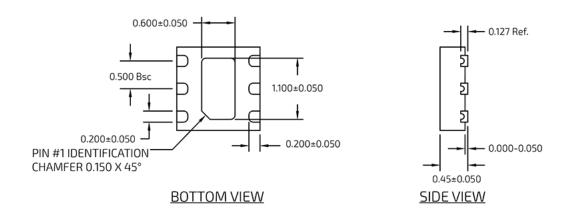






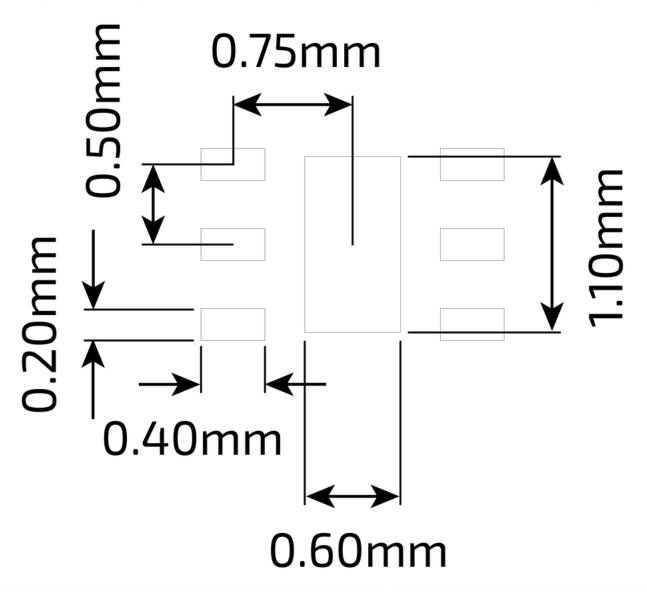






**DFN 6 1.5x1.5mm Package Dimensions** 





**DFN 6 1.5x1.5mm Suggested PCB Footprint (Top View)** 



#### **Package Marking Diagram**

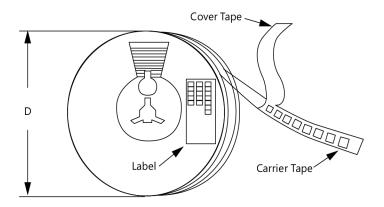


Line 1: "Y" = YEAR (single digit). "WW" = WORK WEEK the Device was assembled.

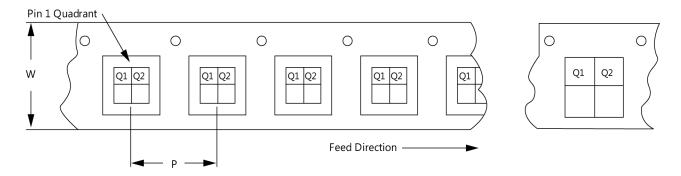
Line 2: "XXXX" = Device Part Number.

#### **Tape and Reel Information**

Guerrilla RF's tape and reel specification complies with Electronics Industries Association (EIA) standards for "Embossed Carrier Tape of Surface Mount Components for Automatic Handling" (reference EIA-481). Devices are loaded with pins down into the carrier pocket with protective cover tape and reeled onto a plastic reel. Each reel is packaged in a cardboard box. There are product labels on the reel, the protective ESD bag, and the outside surface of the box. For the latest reel specifications and package information (including units/reel), please visit Package Manufacturing Information | Guerrilla RF (guerrilla-rf.com).



Tape and Reel Packaging with Reel Diameter Noted (D)



Carrier Tape Width (W), Pitch (P), Feed Direction and Pin 1 Quadrant Information



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## **Revision History**

Revision Date	Description of Change
February 14, 2023	Release Ø Data Sheet. Upgraded Data Sheet to new format. Added new characterization plots. Added new resistor bias curves. Added new switching times.
October 4, 2023	Upgraded Data Sheet to newest format only.
March 13, 2025	Added new Evaluation Board.
April 29, 2025	Raised Maximum Operating Temperature from 105 to 115 °C. Added Maximum Dissipated Power at 115 °C.



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#### **Data Sheet Classifications**

Data Sheet Status	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry-supplied transistor S-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements taken within the Guerrilla RF Applications Lab. Any MIN/MAX limits represented within the data sheet are based solely on <i>estimated</i> part-to-part variations and process spreads. All parametric values are subject to change pending the collection of additional data.
Release Ø	All data based on measurements taken with <i>production-released</i> material. TYP values are based on a combination of ATE and bench-level measurements, with MIN/MAX limits defined using <i>modelled estimates</i> that account for part-to-part variations and expected process spreads. Although unlikely, future refinements to the TYP/MIN/MAX values may be in order as multiple lots are processed through the factory.
Release A-Z	All data based on measurements taken with production-released material <i>derived from multiple lots which have been fabricated over an extended period of time</i> . MIN/MAX limits may be refined over previous releases as more statistically significant data is collected to account for process spreads.

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